

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S22	21648	gate near10 (oxide and (nitride (silicon near3 nitride) Si3N4 ("Si.sub.3" adj3 "N.sub.4"))))	US-PGPU B; USPAT; USOCR	OR	ON	2006/06/20 18:27
S23	47	S22 and (common near5 mask\$3 near5 step)	US-PGPU B; USPAT; USOCR	OR	ON	2006/06/20 18:27
S24	2027	TEOS near2 (silicon near5 oxide)	US-PGPU B; USPAT; USOCR	OR	ON	2006/06/20 18:25
S25	539	TEOS adj1 (silicon near5 oxide)	US-PGPU B; USPAT; USOCR	OR	ON	2006/06/20 18:25
S26	194	TEOS adj1 (silicon near5 oxide)	US-PGPU B	OR	ON	2006/06/20 18:25
S27	4029	gate near10 (oxide and (nitride (silicon near3 nitride) Si3N4 ("Si.sub.3" adj3 "N.sub.4"))))	EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/06/20 18:27
S28	0	S27 and (common near5 mask\$3 near5 step)	EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/06/20 18:27
S29	1167	S27 and mask\$3	EPO; JPO; DERWENT ; IBM_TDB	OR	ON	2006/06/20 18:27